



**THE DATASHEET OF  
ZXMP10A17E6QTA**



## Product Summary

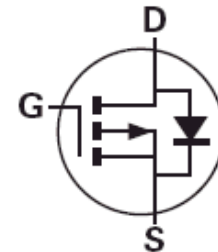
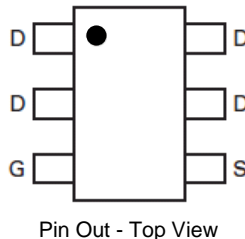
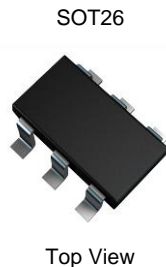
BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
-100V	350mΩ @ V <sub>GS</sub> = -10V	-1.6A
	450mΩ @ V <sub>GS</sub> = -6.0V	-1.4A

## Description

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply



## Features and Benefits

- Fast Switching Speed
- Low Gate Drive
- Low Input Capacitance
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The ZXMP10A17E6Q is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.**

## Mechanical Data

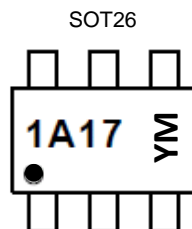
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.018 grams (Approximate)

## Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
ZXMP10A17E6QTA	Automotive	SOT26	3,000/Tape & Reel
ZXMP10A17E6QTAR	Automotive	SOT26	3,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



1A17 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: G = 2019)  
 M = Month (ex: 9 = September)

### Date Code Key

Year	2015	...	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	C	...	G	H	I	J	K	L	M	N	O

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	-100	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Continuous Drain Current	V <sub>GS</sub> = 10V	(Note 6)	-1.6	A	
		T <sub>A</sub> = +70°C (Note 6)	-1.3		
		(Note 5)	-1.3		
Pulsed Drain Current	V <sub>GS</sub> = 10V	(Note 7)	I <sub>DM</sub>	-7.7	A
Continuous Source Current (Body Diode)		(Note 6)	I <sub>S</sub>	-2.1	A
Pulsed Source Current (Body Diode)		(Note 7)	I <sub>SM</sub>	-7.7	A

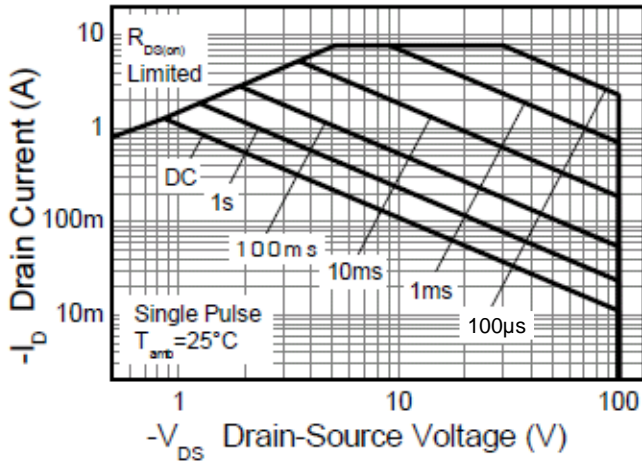
**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P <sub>D</sub>	1.1	W mW/°C
	(Note 6)		8.8	
	(Note 6)		1.7 13.7	
Thermal Resistance, Junction to Ambient	(Note 5)	R <sub>θJA</sub>	113	°C/W
	(Note 6)		73	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

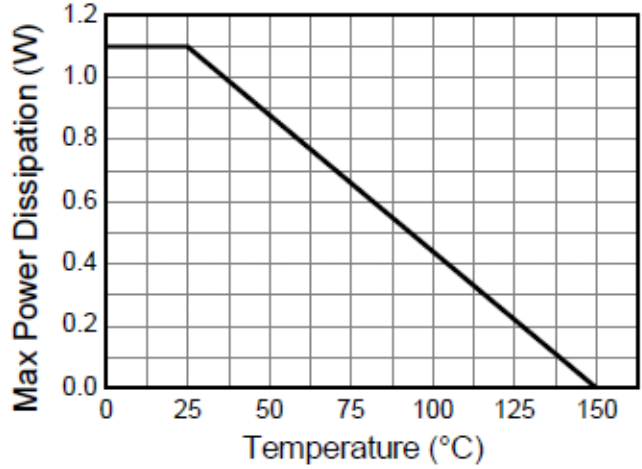
**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-100	—	—	V	I <sub>D</sub> = -250μA, V <sub>GS</sub> = 0V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	-0.5	μA	V <sub>DS</sub> = -100V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-2.0	—	-4.0	V	I <sub>D</sub> = -250μA, V <sub>DS</sub> = V <sub>GS</sub>
Static Drain-Source On-Resistance (Note 8)	R <sub>DS(ON)</sub>	—	—	0.350	Ω	V <sub>GS</sub> = -10V, I <sub>D</sub> = -1.4A
				0.450		V <sub>GS</sub> = -6V, I <sub>D</sub> = -1.2A
Forward Transconductance (Notes 8 & 9)	g <sub>fs</sub>	—	2.8	—	S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -1.4A
Diode Forward Voltage (Note 8)	V <sub>SD</sub>	—	-0.85	-0.95	V	I <sub>S</sub> = -1.7A, V <sub>GS</sub> = 0V
Reverse Recovery Time (Note 9)	t <sub>RR</sub>	—	33	—	ns	I <sub>S</sub> = -1.5A, di/dt = 100A/μs
Reverse Recovery Charge (Note 9)	Q <sub>RR</sub>	—	48	—	nC	
<b>DYNAMIC CHARACTERISTICS</b> (Note 9)						
Input Capacitance	C <sub>iss</sub>	—	424	—	pF	V <sub>DS</sub> = -50V, V <sub>GS</sub> = 0V f = 1MHz
Output Capacitance	C <sub>oss</sub>	—	36.6	—	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	29.8	—	pF	
Total Gate Charge (Note 10)	Q <sub>g</sub>	—	7.1	—	nC	V <sub>GS</sub> = -6V
Total Gate Charge (Note 10)	Q <sub>g</sub>	—	10.7	—	nC	V <sub>GS</sub> = -10V V <sub>DS</sub> = -50V I <sub>D</sub> = -1.4A
Gate-Source Charge (Note 10)	Q <sub>gs</sub>	—	1.7	—	nC	
Gate-Drain Charge (Note 10)	Q <sub>gd</sub>	—	3.8	—	nC	
Turn-On Delay Time (Note 10)	t <sub>D(ON)</sub>	—	3	—	ns	V <sub>DD</sub> = -50V, V <sub>GS</sub> = -10V I <sub>D</sub> = -1A, R <sub>G</sub> = 6.0Ω
Turn-On Rise Time (Note 10)	t <sub>R</sub>	—	3.5	—	ns	
Turn-Off Delay Time (Note 10)	t <sub>D(OFF)</sub>	—	13.4	—	ns	
Turn-Off Fall Time (Note 10)	t <sub>F</sub>	—	7.2	—	ns	

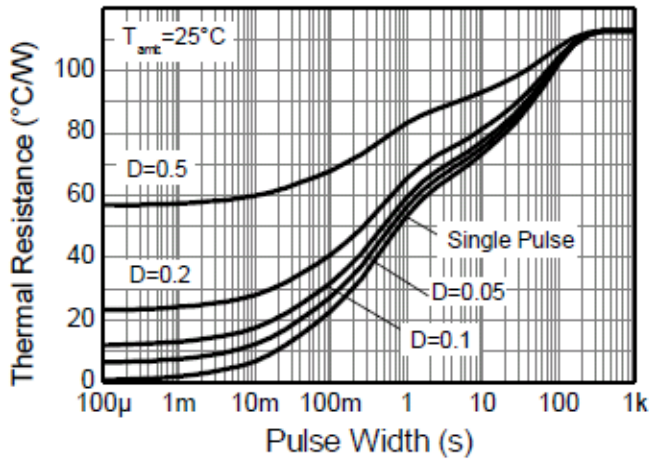
- Notes:
- For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  - Same as Note 5, except the device is measured at t ≤ 5 sec.
  - Same as Note 5, except the device is pulsed with D = 0.05 and pulse width 10μs. The pulse current is limited by the maximum junction temperature.
  - Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
  - For design aid only, not subject to production testing.
  - Switching characteristics are independent of operating junction temperatures.



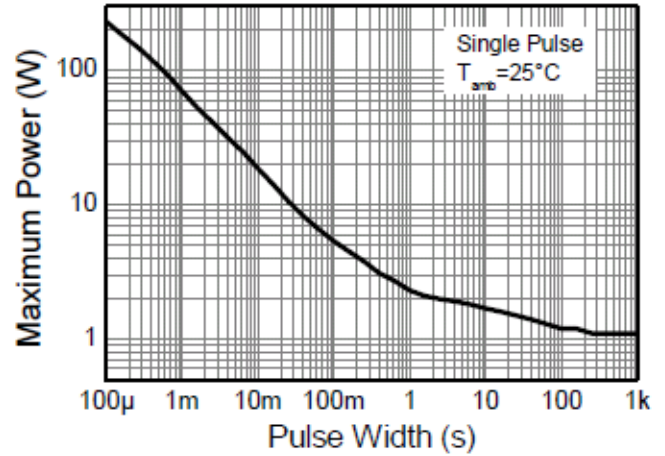
**Safe Operating Area**



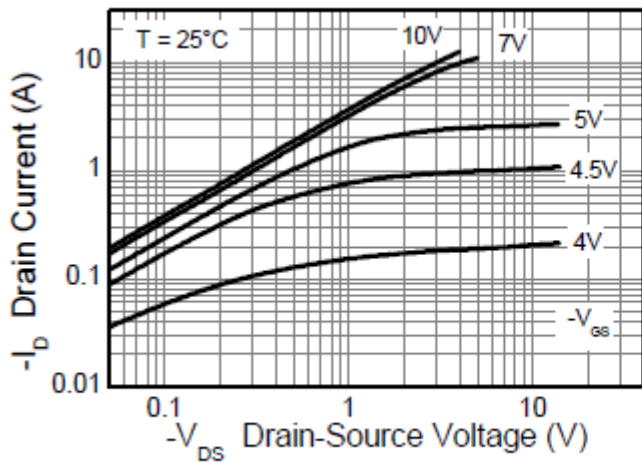
**Derating Curve**



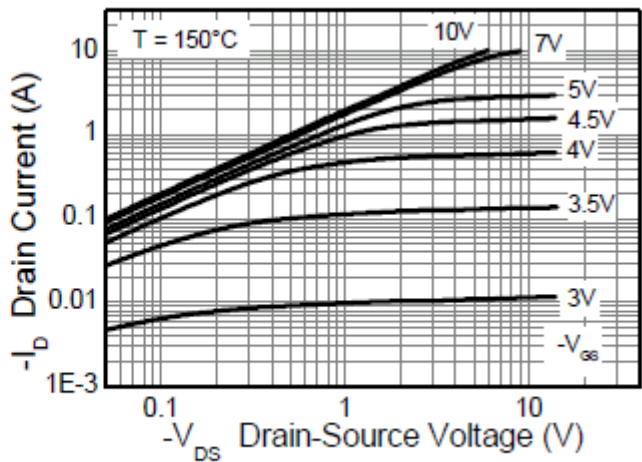
**Transient Thermal Impedance**



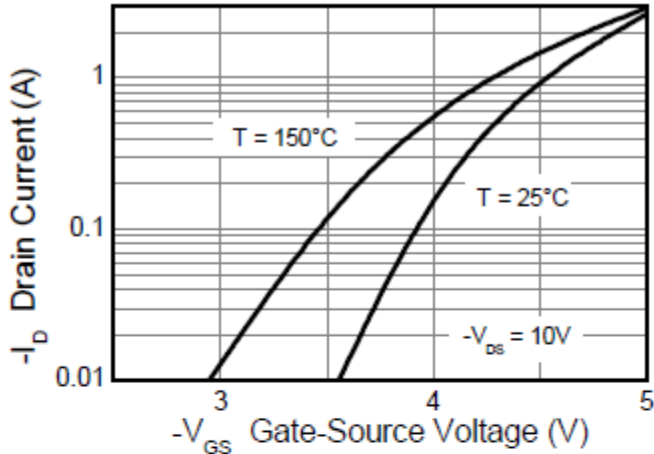
**Pulse Power Dissipation**



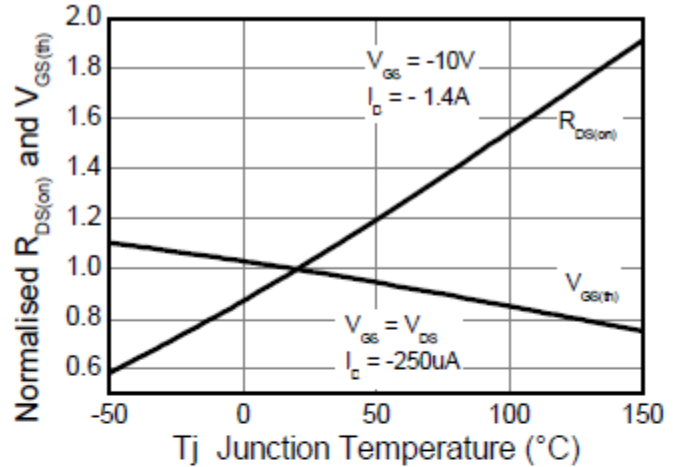
**Output Characteristics**



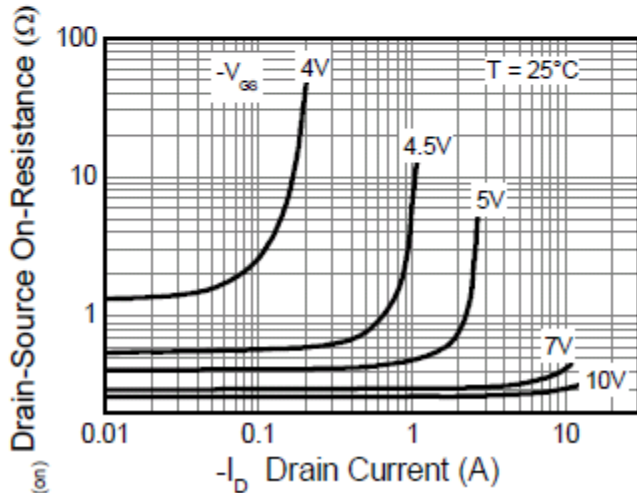
**Output Characteristics**



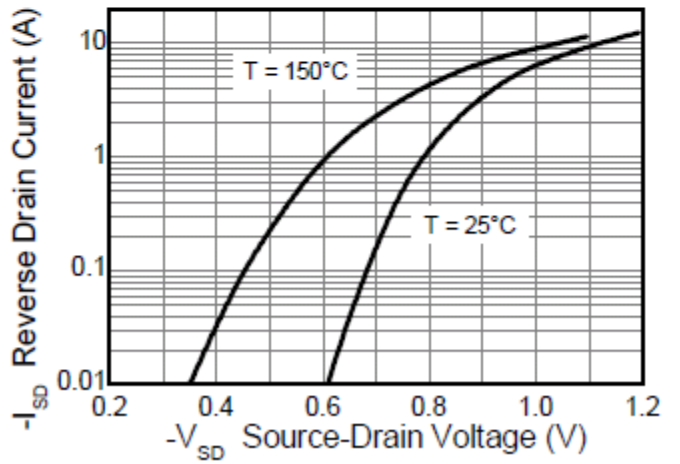
**Typical Transfer Characteristics**



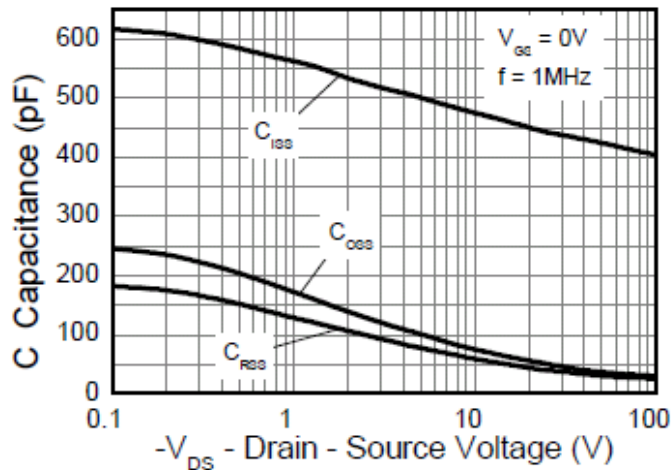
**Normalised Curves v Temperature**



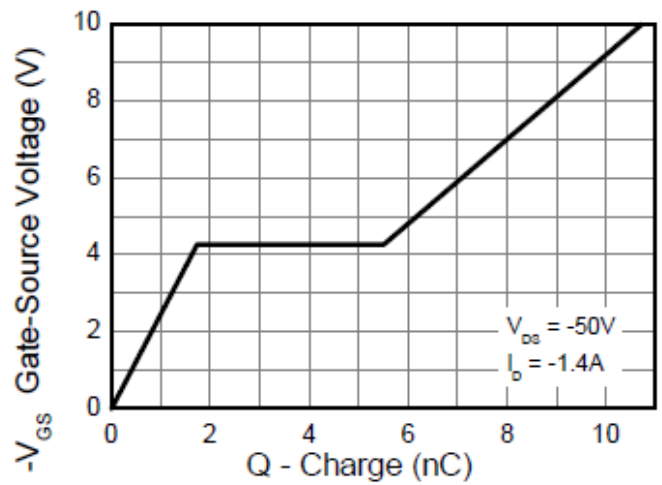
**On-Resistance v Drain Current**



**Source-Drain Diode Forward Voltage**

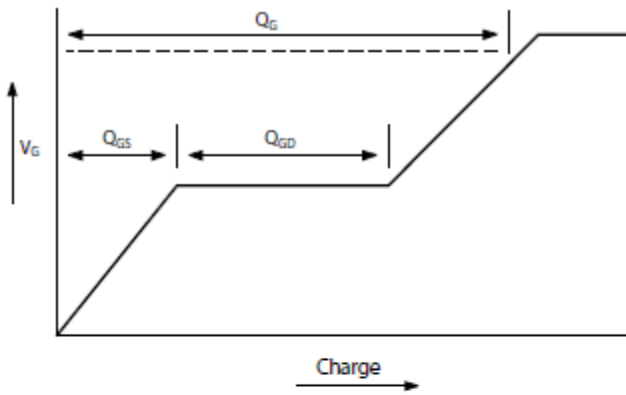


**Capacitance v Drain-Source Voltage**

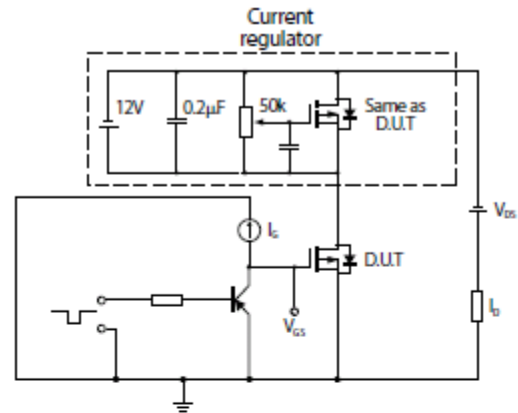


**Gate-Source Voltage v Gate Charge**

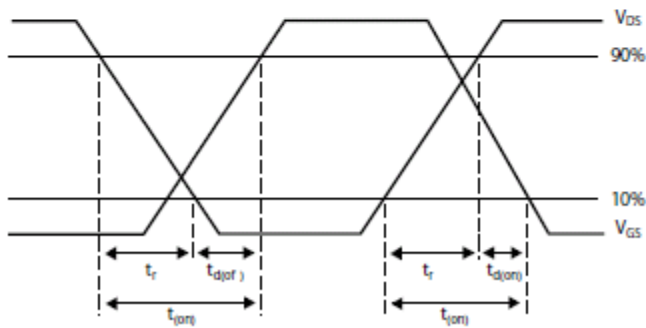
**Test Circuits**



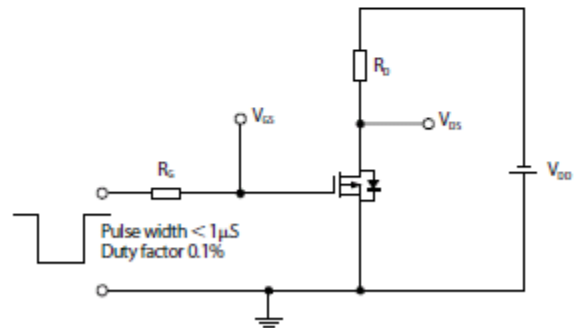
**Basic gate charge waveform**



**Gate charge test circuit**



**Switching time waveforms**

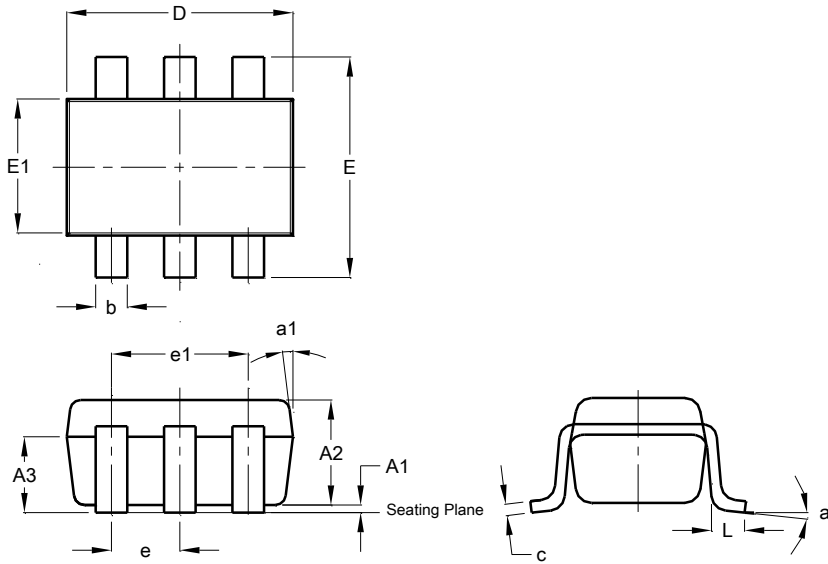


**Switching time test circuit**

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT26**

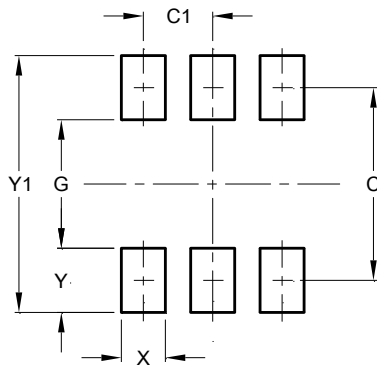


SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT26**

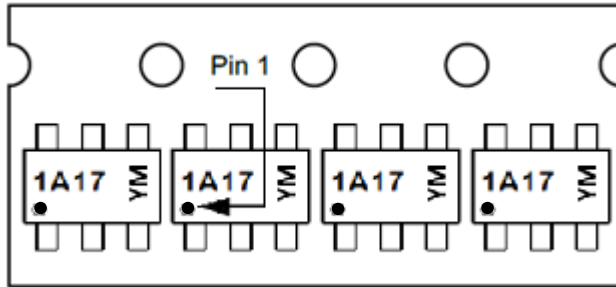


Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

## Tape and Reel Information

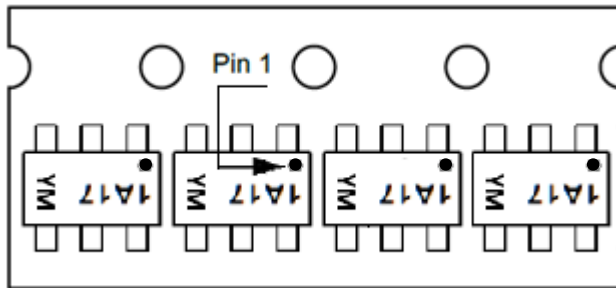
Please see <https://www.diodes.com/assets/Packaging-Support-Docs/Ap02007.pdf> for the latest version.

### ZXMP10A17E6QTA



### ZXMP10A17E6QTAR

Rotate 180 degree of Pin 1 orientation in the carrier tape.



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